

RJK1525DPJ, RJK1525DPE, RJK1525DPF

Silicon N Channel MOS FET High Speed Power Switching

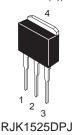
REJ03G0623-0200 Rev.2.00 Jun 30, 2010

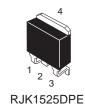
Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0004AE-A RENESAS Package code: PRSS0004AE-B (Package name LDPAK(L)) (Package name LDPAK(S)-(1))



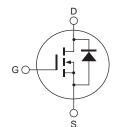




(Package name LDPAK(S)-(2))

RENESAS Package code: PRSS0004AE-C

RJK1525DPF



- 1. Gate
- 2. Drain
- Source
 Drain

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to Source voltage	V_{DSS}	150	V
Gate to Source voltage	V_{GSS}	±30	V
Drain current	I _D	25	А
Drain peak current	I _{D (pulse)} Note1	50	А
Body-Drain diode reverse Drain current	I _{DR}	25	A
Body-Drain diode reverse Drain peak current	I _{DR} (pulse)	50	А
Avalanche current	I _{AP} Note3	17	А
Avalanche energy	E _{AR} Note3	21.6	mJ
Channel dissipation	Pch Note2	75	W
Channel to case thermal impedance	θch-c	1.67	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C

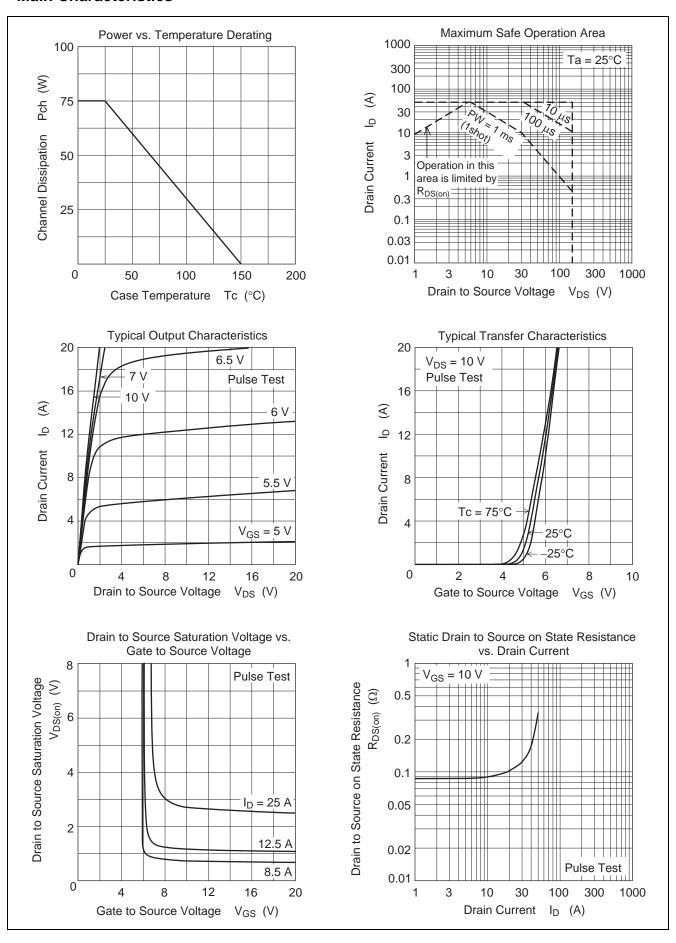
Electrical Characteristics

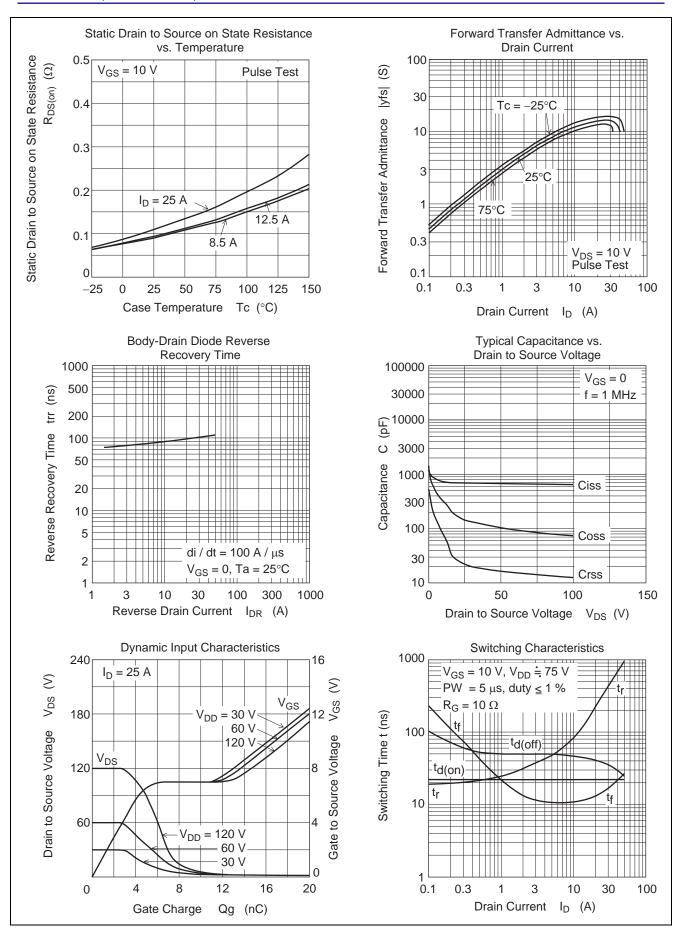
 $(Ta = 25^{\circ}C)$

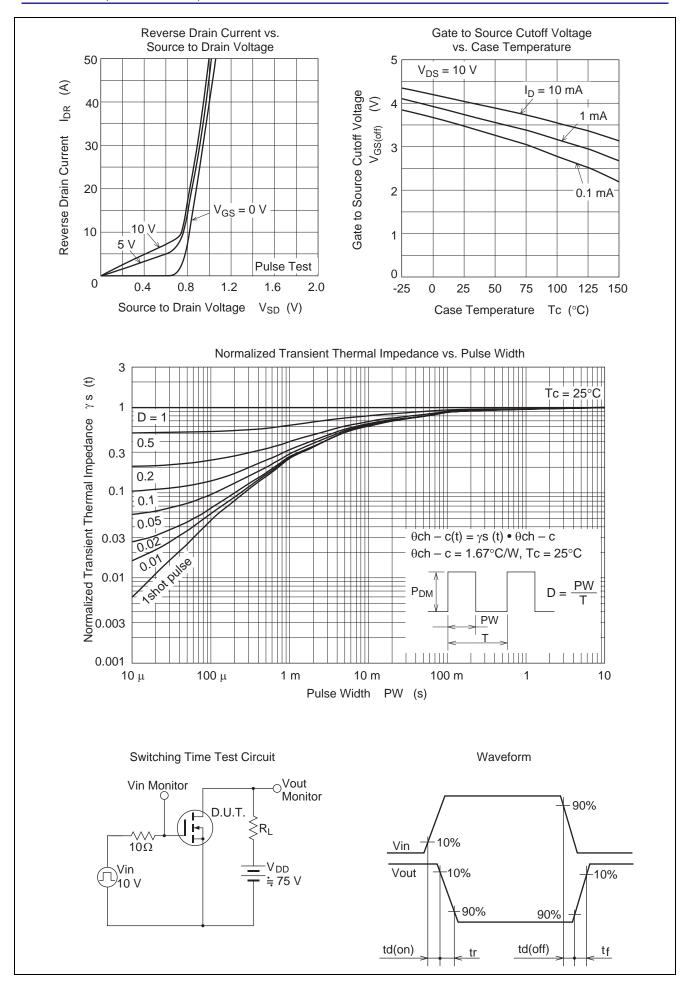
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to Source breakdown voltage	V _{(BR)DSS}	150	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero Gate voltage drain current	I _{DSS}	_	_	1	μΑ	V _{DS} = 150 V, V _{GS} = 0
Gate to Source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Forward transfer admittance	yfs	7	12	_	S	$I_D = 12.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Static Drain to Source on state	R _{DS(on)}	_	0.093	0.110	Ω	$I_D = 12.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Input capacitance	Ciss	_	680	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	150	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		22		pF	
Turn-on delay time	td(on)		22		ns	I _D = 12.5 A
Rise time	tr		110		ns	V _{GS} = 10 V
Turn-off delay time	td(off)	_	45	_	ns	$R_L = 6 \Omega$
Fall time	tf	_	12	_	ns	$Rg = 10 \Omega$
Total Gate charge	Qg		18		nC	V _{DD} = 120 V
Gate to Source charge	Qgs	_	4.5	_	nC	V _{GS} = 10 V I _D = 25 A
Gate to Drain charge	Qgd		9		nC	
Body-Drain diode forward voltage	V_{DF}	_	0.95	1.50	V	I _F = 25 A, V _{GS} = 0 Note4
Body-Drain diode reverse recovery time	trr		100		ns	$I_F = 25 \text{ A}, V_{GS} = 0$
Body-Drain diode reverse recovery	Qrr	_	0.4	_	μС	diF/dt = 100 A/μs
charge						

Notes: 4. Pulse test

Main Characteristics

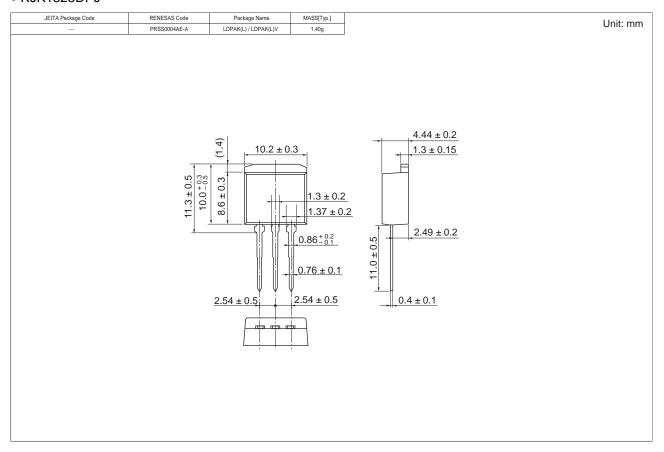




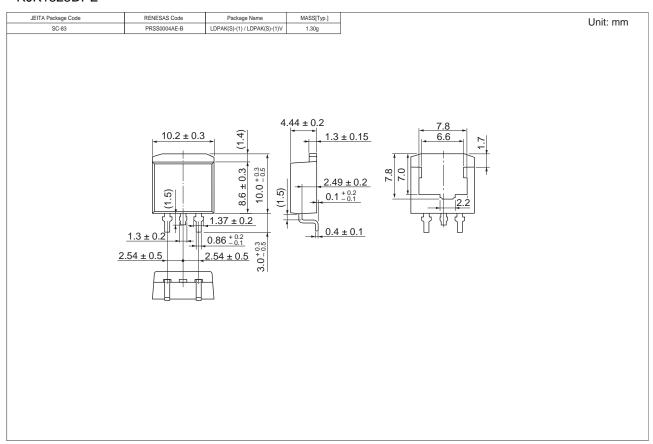


Package Dimensions

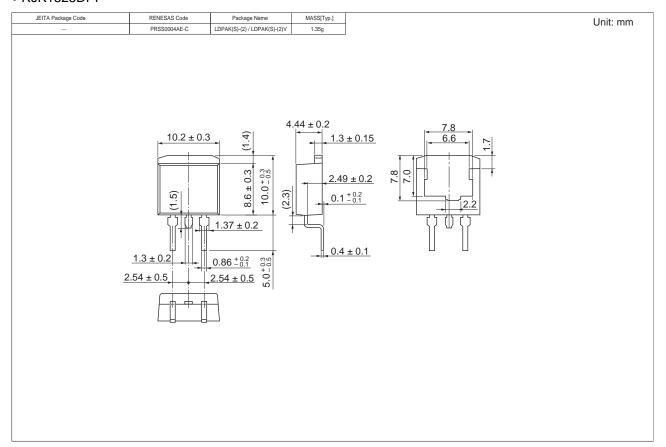
• RJK1525DPJ



• RJK1525DPE



• RJK1525DPF



Ordering Information

Part Name	Quantity	Shipping Container
RJK1525DPE-LE	1000 pcs	Taping

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